Dual buffer/line driver; 3-state Rev. 4 — 16 January 2019

**Product data sheet** 

### 1. General description

The 74AHC2G241; 74AHCT2G241 is a high-speed Si-gate CMOS device.

The 74AHC2G241; 74AHCT2G241 is a dual non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs  $1\overline{OE}$  and 2OE. A HIGH level at pin  $1\overline{OE}$  causes output 1Y to assume a high-impedance OFF-state. A LOW level at pin 2OE causes output 2Y to assume a high-impedance OFF-state. Schmitt-trigger action at all inputs makes the circuit highly tolerant for slower input rise and fall times.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

### 2. Features and benefits

- Symmetrical output impedance
- High noise immunity
- ESD protection:
  - HBM JESD22-A114E: exceeds 2000 V
  - MM JESD22-A115-A: exceeds 200 V
  - CDM JESD22-C101C: exceeds 1000 V
- Low power dissipation
- Balanced propagation delays
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

### 3. Ordering information

### Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AHC2G241DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2					
74AHC2G241DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads;	SOT765-1					
74AHCT2G241DC			body width 2.3 mm						

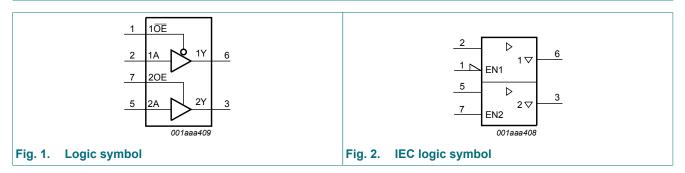
# nexperia

## 4. Marking

Table 2. Marking							
Type number	Marking code[1]						
74AHC2G241DP	A241						
74AHC2G241DC	A41						
74AHCT2G241DC	C41						

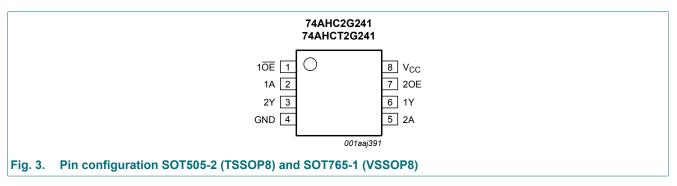
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description								
Symbol	Pin	Description						
1 <del>0E</del>	1	output enable input (active LOW)						
1A	2	data input						
2Y	3	data output						
GND	4	ground (0 V)						
2A	5	data input						
1Y	6	data output						
20E	7	output enable input (active HIGH)						
V <sub>CC</sub>	8	supply voltage						

# 7. Functional description

### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input		Output	Input	Output	
1 <del>0E</del>	1A	1Y	20E	2A	2Y
L	L	L	Н	L	L
L	Н	Н	Н	Н	Н
Н	Х	Z	L	Х	Z

# 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < -0.5 V	[1]	-20	-	mA
I <sub>ОК</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$-0.5 V < V_O < V_{CC} + 0.5 V$		-	±25	mA
I <sub>CC</sub>	supply current			-	75	mA
I <sub>GND</sub>	ground current			-75	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ = -40 °C to +125 °C	[2]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.

# 9. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74	AHC2G2	41	74	Unit		
			Min	Тур	Max	Min	Тур	Max	-
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	$V_{CC}$ = 3.3 V ± 0.3 V	-	-	100	-	-	-	ns/V
	and fall rate	$V_{CC}$ = 5.0 V ± 0.5 V	-	-	20	-	-	20	ns/V

# **10. Static characteristics**

#### **Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	G241							1		
VIH	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		$I_{O}$ = -8.0 mA; $V_{CC}$ = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		$I_{O}$ = 50 µA; $V_{CC}$ = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	0.25	-	2.5	-	10	μA
lı	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	1.0	-	10	-	40	μA
CI	input capacitance		-	1.5	10	-	10	-	10	pF

### Dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	1
74AHCT	2G241	1								
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC}$ = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -8.0 mA	3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>		$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	0.25	-	2.5	-	10	μA
I <sub>I</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	1.0	-	10	-	40	μA
ΔI <sub>CC</sub>	additional supply current	per input pin; V <sub>I</sub> = 3.4 V; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance		-	1.5	10	-	10	-	10	pF

# **11. Dynamic characteristics**

### Table 8. Dynamic characteristics

GND = 0 V; for test circuit see Fig. 7.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C to +125 °C		Unit
				Min	Тур	Мах	Min	Max	Min	Мах	1
74AHC2	G241								· ·		
t <sub>pd</sub>	propagation	nA to nY; see Fig. 4	[1]								
	delay	V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	4.7	8.0	1.0	9.5	1.0	11.5	ns
		C <sub>L</sub> = 50 pF		-	6.6	11.5	1.0	13.0	1.0	14.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	4.7	7.5	1.0	8.5	1.0	9.5	ns
t <sub>en</sub>	enable time	1OE to 1Y; see Fig. 5	[1]								
		V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	5.0	8.0	1.0	9.5	1.0	11.5	ns
		C <sub>L</sub> = 50 pF		-	6.9	11.5	1.0	13.0	1.0	14.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.6	5.1	1.0	6.0	1.0	6.5	ns
		C <sub>L</sub> = 50 pF		-	4.9	7.5	1.0	8.5	1.0	9.5	ns
		2OE to 2Y; see Fig. 6	[1]								
		V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	4.9	8.0	1.0	9.5	1.0	10.0	ns
		C <sub>L</sub> = 50 pF		-	7.0	11.5	1.0	13.0	1.0	14.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.6	5.6	1.0	6.3	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	5.4	8.0	1.0	9.0	1.0	9.5	ns
t <sub>dis</sub>	disable time	1OE to 1Y; see Fig. 5	[1]								
		V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	6.0	9.7	1.0	11.5	1.0	12.5	ns
		C <sub>L</sub> = 50 pF		-	8.3	13.2	1.0	15.0	1.0	16.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	4.1	6.8	1.0	8.0	1.0	8.5	ns
		C <sub>L</sub> = 50 pF		-	5.7	8.8	1.0	10.0	1.0	11.0	ns
		2OE to 2Y; see Fig. 6	[1]								
		V <sub>CC</sub> = 3.0 V to 3.6 V	[2]								
		C <sub>L</sub> = 15 pF		-	6.3	9.7	1.0	11.5	1.0	12.5	ns
		C <sub>L</sub> = 50 pF		-	9.0	13.2	1.0	15.0	1.0	16.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								1
		C <sub>L</sub> = 15 pF		-	4.3	6.8	1.0	8.0	1.0	8.5	ns
		C <sub>L</sub> = 50 pF		-	6.1	8.8	1.0	10.0	1.0	11.0	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	[4]	-	10	-	-	-	-	-	pF

### Dual buffer/line driver; 3-state

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to +125 °C		Unit
			-	Min	Тур	Max	Min	Max	Min	Max	
74AHCT	2G241								1	1	
t <sub>pd</sub>	propagation	nA to nY; see Fig. 4	[1]								
	delay	V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		C <sub>L</sub> = 50 pF		-	4.7	7.5	1.0	8.5	1.0	9.5	ns
t <sub>en</sub>	enable time	1OE to 1Y; see Fig. 5	[1]								
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.9	5.1	1.0	6.0	1.0	6.5	ns
		C <sub>L</sub> = 50 pF		-	5.1	7.5	1.0	8.5	1.0	9.5	ns
		2OE to 2Y; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	3.4	5.6	1.0	6.3	1.0	6.5	ns
		C <sub>L</sub> = 50 pF		-	4.8	7.5	1.0	9.0	1.0	9.5	ns
t <sub>dis</sub>	disable time	1OE to 1Y; see Fig. 5	[1]								
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	4.5	6.8	1.0	8.0	1.0	8.5	ns
		C <sub>L</sub> = 50 pF		-	6.1	8.8	1.0	10.0	1.0	11.0	ns
		2OE to 2Y; see Fig. 6	[1]								
		V <sub>CC</sub> = 4.5 V to 5.5 V	[3]								
		C <sub>L</sub> = 15 pF		-	4.0	6.8	1.0	8.0	1.0	8.5	ns
		C <sub>L</sub> = 50 pF		-	5.7	8.8	1.0	10.0	1.0	11.0	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $C_L$ = 50 pF; f <sub>i</sub> = 1 MHz; $V_I$ = GND to $V_{CC}$	[4]	-	10	-	-	-	-	-	pF

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

 $t_{en}$  is the same as  $t_{\text{PZL}}$  and  $t_{\text{PZH}}.$ 

- $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ . Typical values are measured at V<sub>CC</sub> = 3.3 V. [2]
- Typical values are measured at  $V_{CC}$  = 5.0 V. [3]
- $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  (µW).  $P_D = C_{PD} x V_{CC}^2 x f_i + \sum (C_L x V_{CC}^2 x f_o)$  where: [4]

 $f_i$  = input frequency in MHz;

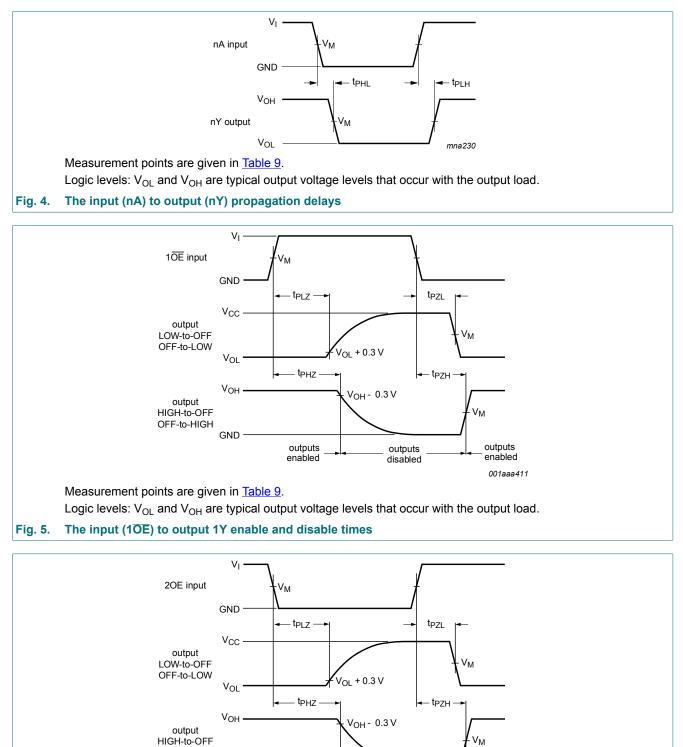
fo = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts.

### Dual buffer/line driver; 3-state





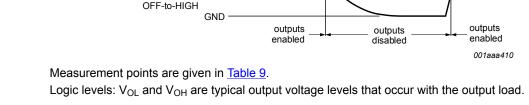


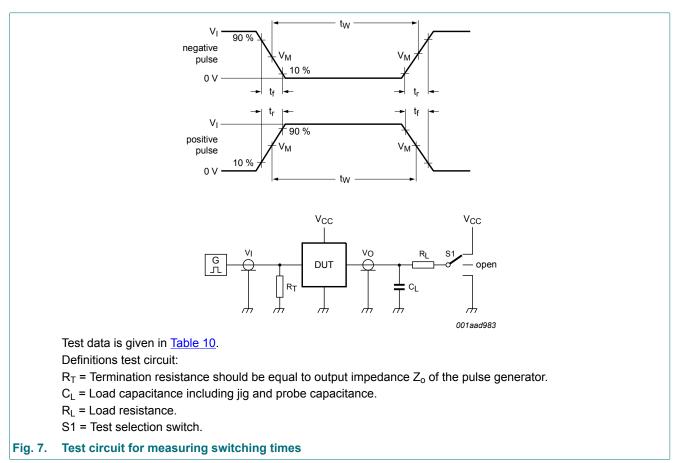
Fig. 6. The input (2OE) to output 2Y enable and disable times

74AHC\_AHCT2G241

### Dual buffer/line driver; 3-state

Table	9.	Measurement points
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Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74AHC2G241	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74AHCT2G241	1.5 V	0.5V <sub>CC</sub>

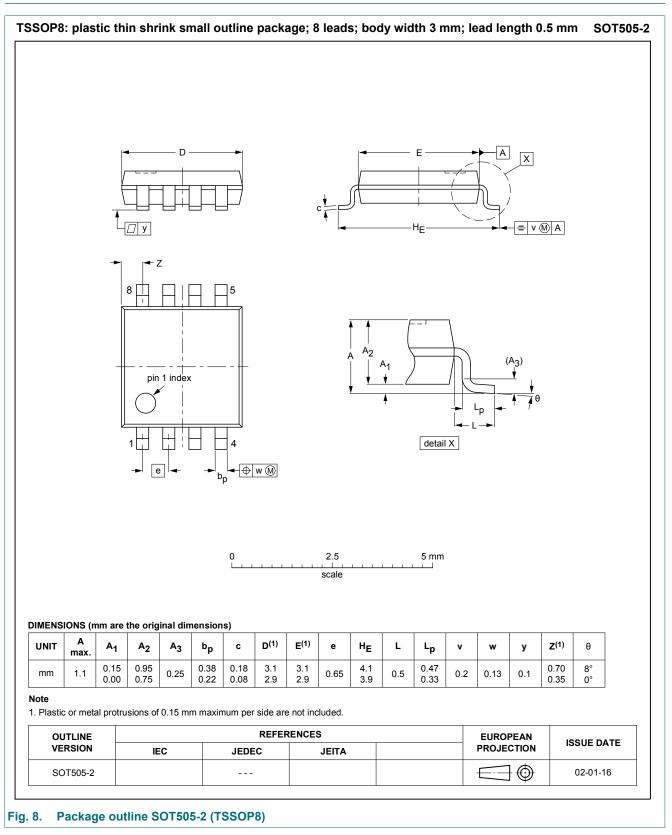


### Table 10. Test data

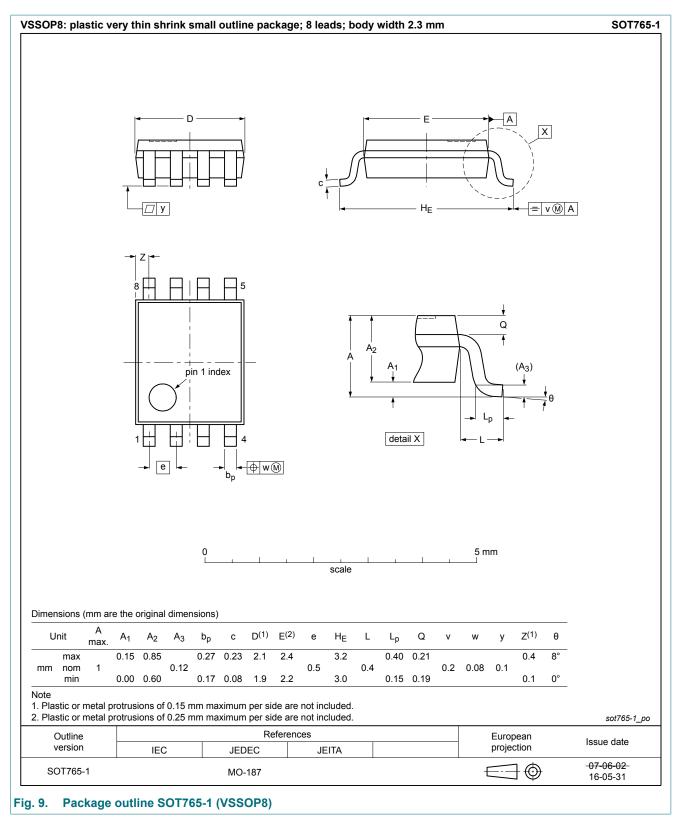
Туре	Input		Load		S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74AHC2G241	V <sub>CC</sub>	≤ 3 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>
74AHCT2G241	3 V	≤ 3 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

### Dual buffer/line driver; 3-state

# 12. Package outline



### Dual buffer/line driver; 3-state



# 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AHC_AHCT2G241 v.4	20190116	Product data sheet	-	74AHC_AHCT2G241 v.3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74AHCT2G241DP, 74AHC2G241GD and 74AHCT2G241GD removed.</li> </ul>					
74AHC_AHCT2G241 v.3	20130513	Product data sheet	-	74AHC_AHCT2G241 v.2		
Modifications:	For type number 74AHC2G241GD and 74AHCT2G241GD XSON8U has changed to XSON8.					
74AHC_AHCT2G241 v.2	20090113	Product data sheet	-	74AHC_AHCT2G241 v.1		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Added type number 74AHC2G241GD and 74AHCT2G241GD (XSON8U package).</li> </ul>					
74AHC_AHCT2G241 v.1	20040310	Product data	-	-		

# 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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#### Dual buffer/line driver; 3-state

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Product data sheet

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